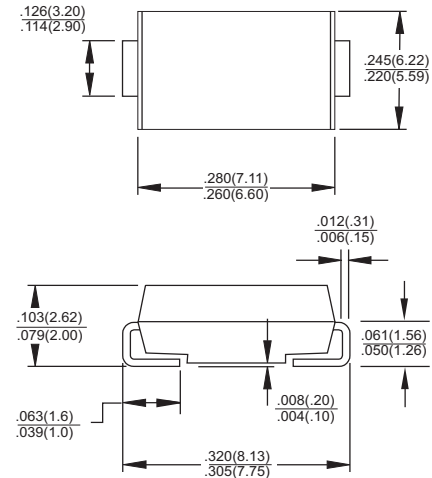




### Features

- ✧ Glass passivated junction chip
- ✧ For surface mounted applications
- ✧ Low profile package
- ✧ Built-in strain relief
- ✧ Ideal for automated placement
- ✧ Easy pick and place
- ✧ Super fast recovery time for high efficiency
- ✧ Glass passivated chip junction
- ✧ High temperature soldering:  
260°C/10 seconds at terminals
- ✧ Plastic material used carries Underwriters  
Laboratory Classification 94V-0



Dimensions in inches and (millimeters)

### Mechanical Data

- ✧ Cases: Molded plastic
- ✧ Terminals: Pure tin plated, lead free.
- ✧ Polarity: Indicated by cathode band
- ✧ Packaging: 16mm tape per EIA STD RS-481
- ✧ Weight: 0.21 gram

### Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	ES 3A	ES 3B	ES 3C	ES 3D	ES 3F	ES 3G	ES 3H	ES 3J	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	$V_{RMS}$	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current See Fig. 1	$I_{(AV)}$	3.0								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method) @ $T_L = 100^\circ\text{C}$	$I_{FSM}$	100								A
Maximum Instantaneous Forward Voltage @ 3.0A	$V_F$	0.95				1.3		1.7		V
Maximum DC Reverse Current @ $T_A = 25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_A = 100^\circ\text{C}$	$I_R$					10				uA
						500				uA
Maximum Reverse Recovery Time ( Note 1 )	$T_{rr}$					35				nS
Typical Junction Capacitance ( Note 2 )	$C_j$	45				30				pF
Typical Thermal Resistance (Note 3)	$R_{\theta JA}$ $R_{\theta JL}$					47				°C /W
						12				
Operating Temperature Range	$T_J$	-55 to +150								°C
Storage Temperature Range	$T_{STG}$	-55 to +150								°C

- Notes:
1. Reverse Recovery Test Conditions:  $I_F = 0.5A$ ,  $I_R = 1.0A$ ,  $I_{RR} = 0.25A$
  2. Measured at 1 MHz and Applied  $V_R = 4.0$  Volts
  3. Units Mounted on P.C.B. with 0.6" x 0.6" (16mm x 16mm) Copper Pad Areas

## RATINGS AND CHARACTERISTIC CURVES (ES3A THRU ES3J)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

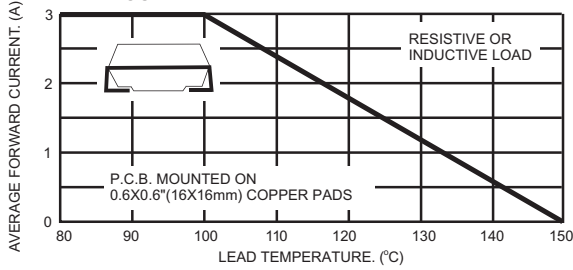


FIG.2- MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

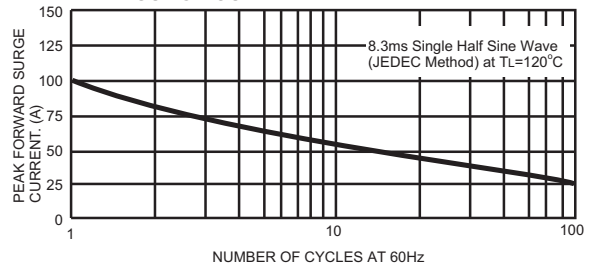


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

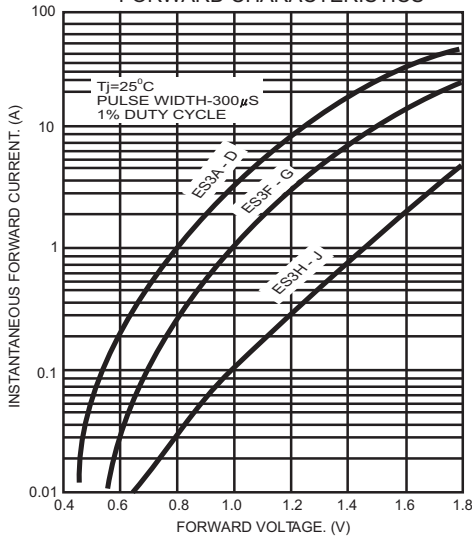


FIG.4- TYPICAL REVERSE CHARACTERISTICS

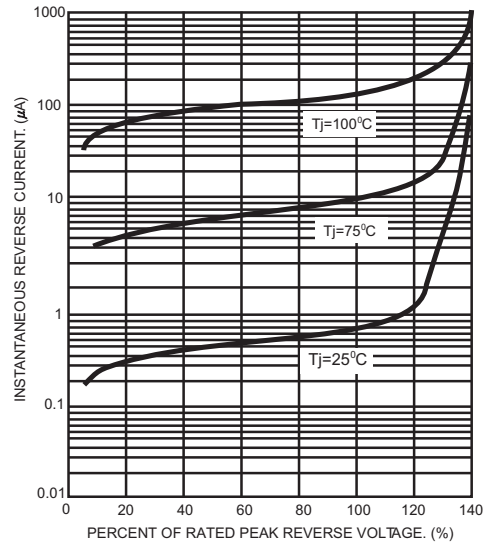


FIG.5- TYPICAL JUNCTION CAPACITANCE

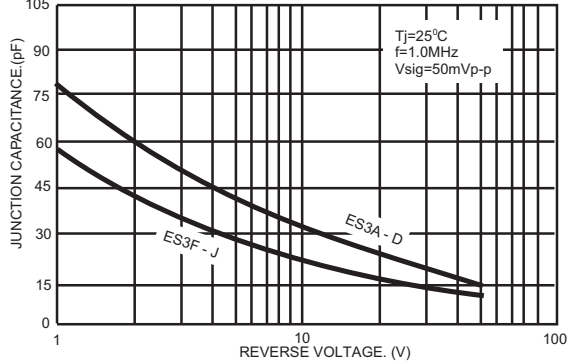


FIG.6- TYPICAL TRANSIENT THERMAL IMPEDANCE

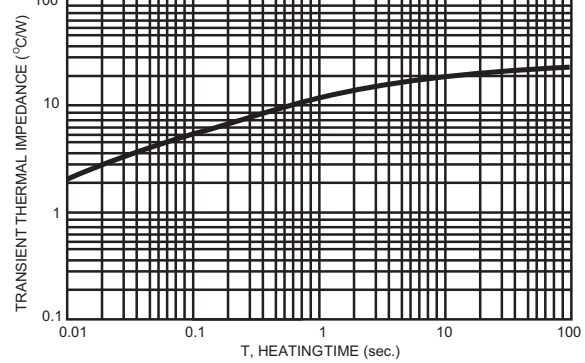


FIG.7- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

